







Seminarankündigung

Dienstag, 27. Juli 2021 13:00 Uhr

ONLINE via ZOOM

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"Selective area epitaxy for electronic and photonic device integration"

Selective growth techniques for semiconductors became very popular thanks to the large interest in nanowire structures and have flourished accordingly over the past 20 years. In this talk I will report on activities that have been pursued in our group by the use of selective area growth in templates for III-V semiconductors on Si for microelectronic (transistor) and photonic (laser) applications. Here key emphasis is given to an integration path resembling traditional manufacturing processes. On a more exploratory side, I will motivate and review our activities on the synthesis of semiconductors in thermodynamic less stable crystal phases.

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